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By: Date: April 28, 1998IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Gunther Plasa  
Serial No. : 09/020,872  
Filed : February 9, 1998  
Title : Method for Producing a Memory Cell

P R E L I M I N A R Y A M E N D M E N T

Hon. Commissioner of Patents and Trademarks,  
Washington, D. C. 20231

S i r :

Preliminary to examination, kindly amend the above-identified application as follows:

In the Specification:

Page 12, line 3, after "capacitance" insert, "and as a control gate of the EEPROM".

Remarks:

Reconsideration of the application is requested.

The application has been revised in order to more clearly describe the invention. Support for the insertion on page 12 of the specification can be found on page 5, lines 10-17. The

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